

## 935nm DFB Laser diode for Seed Laser



### Description

The PL-DFB-935-B-A81 935nm DFB laser diode module made by LD-PD is a cost effective, highly coherent laser source. The DFB laser diode chip is packaged in an industry standard hermetically sealed 14 pin butterfly package with TEC and PD Built in.

### Features

- Narrow Linewidth < 2MHz
- Excellent wavelength control and stability
- Industry Standard 14 pin Butterfly package
- Mode-Hop free tuning
- Excellent reliability
- Customer specific wavelengths available

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## Advantages

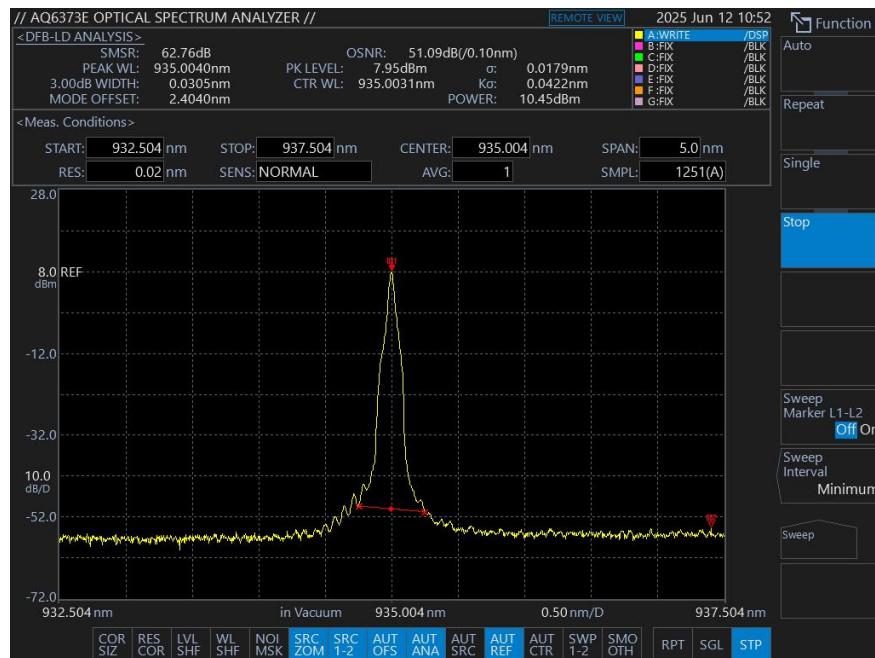
- Tunable diode laser absorption spectroscopy
- Seed laser
- Fiber laser

## Laser Specifications

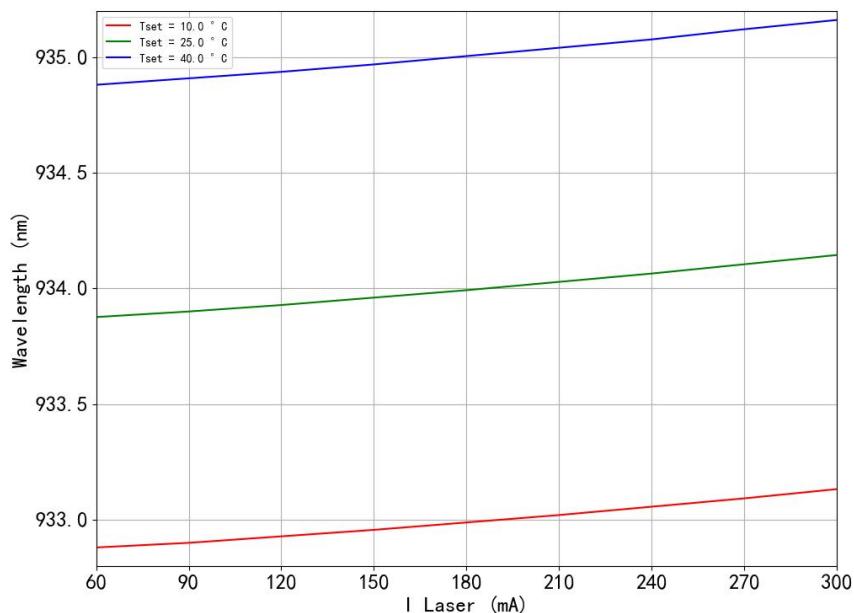
Electrical/Optical Characteristics( $T_{sub}=25^{\circ}\text{C}$ , CW bias unless stated otherwise)

Parameter	Symbol	Min	Typ	Max	Unit
Centre Wavelength	$\lambda$	934	935	936	nm
Side Mode Suppression Ratio	SMSR	30	40		dB
Threshold Current	$I_{th}$		20	30	mA
Operating Current	$I_{op}$		250	300	mA
Chip output Power	$P_f$		40	50	mW
Quantum Efficiency	$\eta$	0.08	0.15	0.2	mW/mA
Current Tuning Coefficient	$\Delta\lambda/\Delta I$		0.005		nm/mA
Temperature Tuning Coefficient	$\Delta\lambda/\Delta T$		0.09		nm/K
Forward Voltage	$V_f$		1.3	2	V
Thermistor Resistance	$R_T$	9.5	10	10.5	K $\Omega$
Thermistor Temp. Coefficient			-4.4		%/ $^{\circ}\text{C}$
Connector		FC/APC			

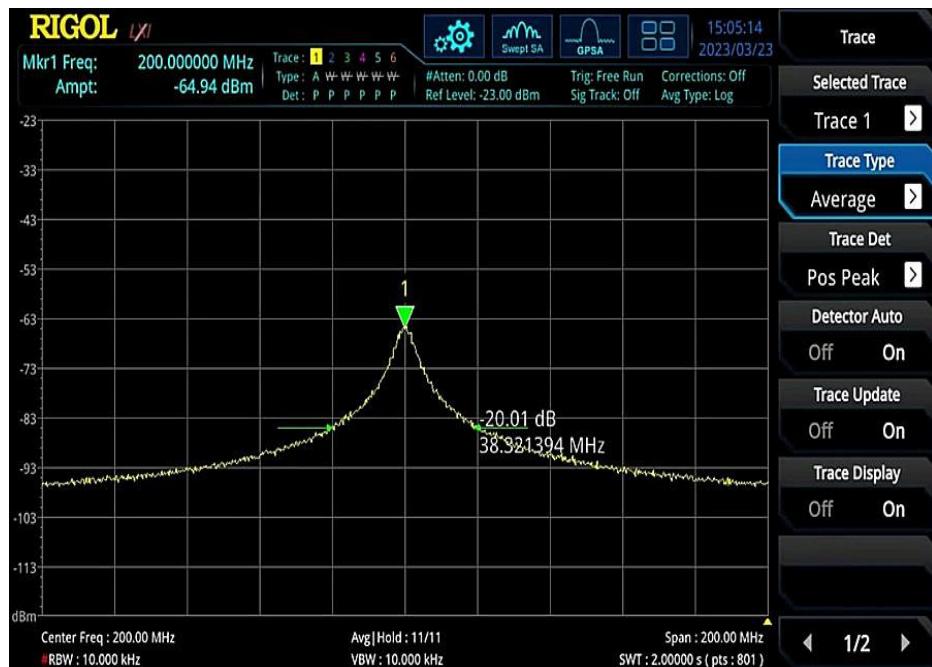
## Spectrum



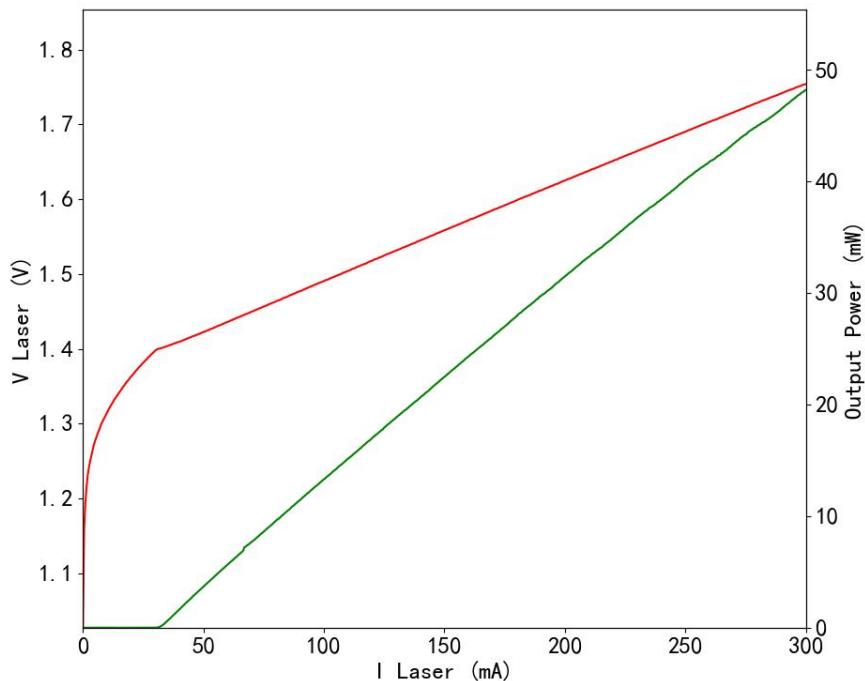
## Tuning Characteristics



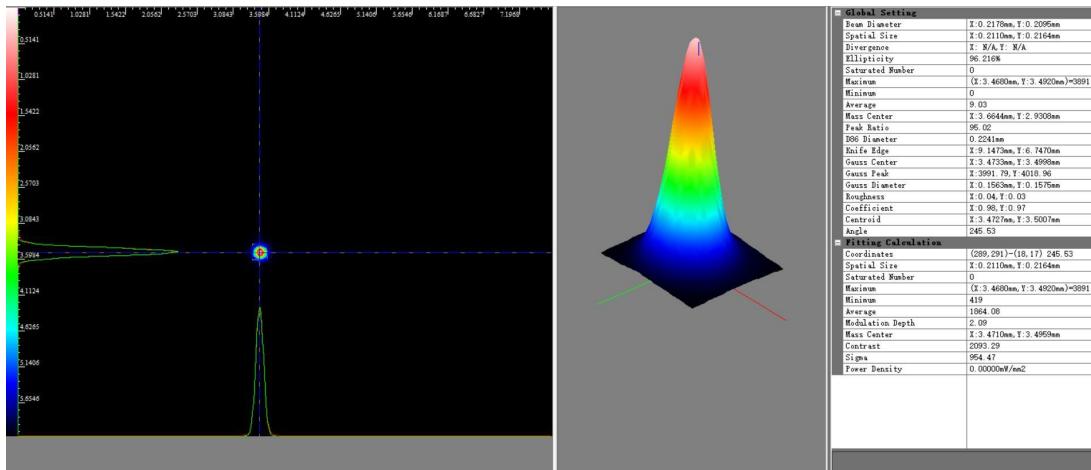
## DFB Linewidth Testing Result



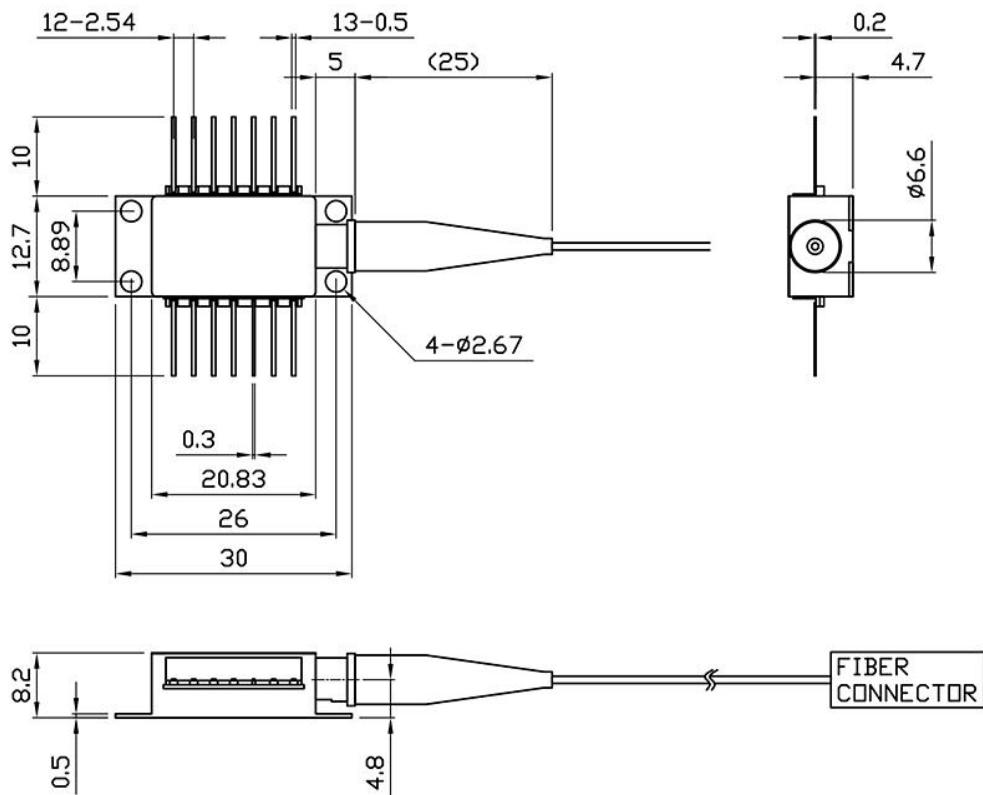
## L-I Curve



## Beam Quality

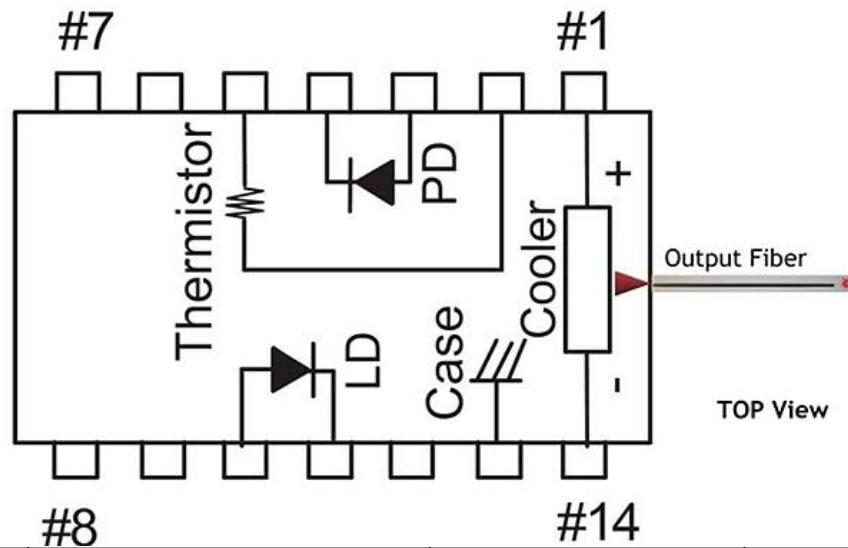


## Package Size



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## Pin definition



	#7	#1	#14
1	Thermoelectric Cooler (+)	8	N/C
2	Thermistor	9	N/C
3	PD Monitor Anode (-)	10	Laser Anode (+)
4	PD Monitor Cathode (+)	11	Laser Cathode (-)
5	Thermistor	12	N/C
6	N/C	13	Case Ground
7	N/C	14	Thermoelectric Cooler (-)

### Absolute Maximum Ratings

Item	Unit	Min	Typ	Max
Case Temperature	°C	-5	25	70
Chip Temperature	°C	+10	25	40
Operating Current	mA	0	120	150
Forward Voltage	V	0.8	1.2	2.1
TEC Current	A	-	1.2	1.2
Reverse Voltage (LD)	V	-	-	2.0
Reverse Voltage(PD)	V	-	-	20

## Ordering Info

PL-DFB- □□□-☆-A8▽- XX

□□□: Wavelength

972.4: 972.4nm

1030: 1030nm

1532: 1532nm

1392: 1392nm

1512: 1512nm

1567: 1567nm

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1653.7: 1653.7nm

☆ : Output Power

A: 20-30mW

B: 40-60mW

▽: Wavelength Tolerance

1: ±1nm

2: ±2nm

XX: Fiber and Connector Type

SA=HI1060+ FC/APC

SP=HI1060+ FC/PC

PA=PM980 Fiber+ FC/APC

PP=PM980 Fiber+ FC/PC